New Product

ESH3B, ESH3C & ESH3D

Vishay General Semiconductor

Surface Mount Ultrafast Plastic Rectifiers



DO-214AB (SMC)

FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Ultrafast recovery times for high efficiency
- · Low forward voltage, low power loss
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer and automotive.

MECHANICAL DATA

Case: DO-214AB (SMC)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

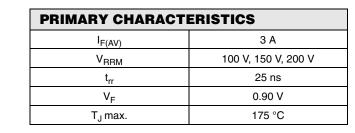
E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT	
Device marking code		EHB	EHC	EHD		
Maximum repetitive peak reverse voltage	V _{RMM}	100	150	200	V	
Maximum RMS voltage	V _{RMS}	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	100	150	200	V	
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	3.0		А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	125		А		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 175		°C		



ROHS COMPLIANT



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ELECTRICAL CHARACTERISTICS ($T_A = 25 \degree C$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage $^{(1)}$	I _F = 3 A		V _F	0.90	V	
Maximum DC reverse current at rated DC blocking voltage		T _A = 25 °C T _A = 125 °C	I _R	5.0 150	μΑ	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	25	ns	
Typical reverse recovery time	$I_F = 3 \text{ A}, V_R = 30 \text{ V},$ dl/dt = 50 A/µs, $I_{rr} = 10 \% I_{RM}$	T _J = 25 °C T _J = 100 °C	t _{rr}	40 55	ns	
Typical stored charge	$I_F = 3 \text{ A}, V_R = 30 \text{ V},$ dl/dt = 50 A/µs, $I_{rr} = 10 \% I_{RM}$	T _J = 25 °C T _J = 100 °C	Q _{rr}	25 60	nC	
Typical junction capacitance	4.0 V, 1 MHz		CJ	70	pF	

Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT		
Typical thermal resistance ⁽¹⁾	$R_{ extsf{ heta}JA}$ $R_{ extsf{ heta}JL}$	50 15			°C/W		

Note:

(1) Units mounted on P.C.B. with 12.0 x 12.0 mm land areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH3D-E3/57T	0.211	57T	850	7" diameter plastic tape and reel		
ESH3D-E3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel		
ESH3DHE3/57T (1)	0.211	57T	850	7" diameter plastic tape and reel		
ESH3DHE3/9AT ⁽¹⁾	0.211	9AT	3500	13" diameter plastic tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

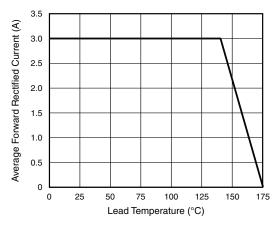


Figure 1. Maximum Forward Current Derating Curve

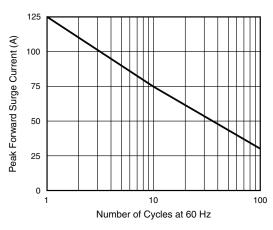


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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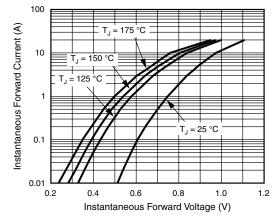


Figure 3. Typical Instantaneous Forward Characteristics

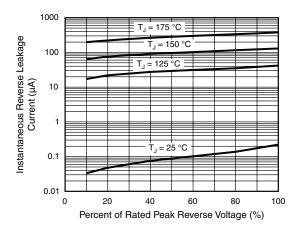


Figure 4. Typical Reverse Leakage Characteristics

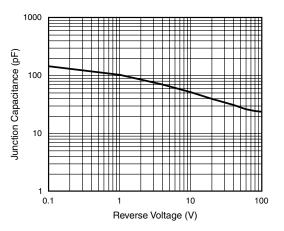


Figure 5. Typical Junction Capacitance

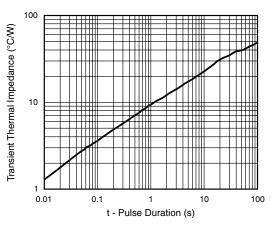
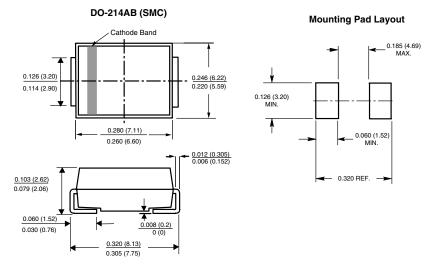


Figure 6. Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



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